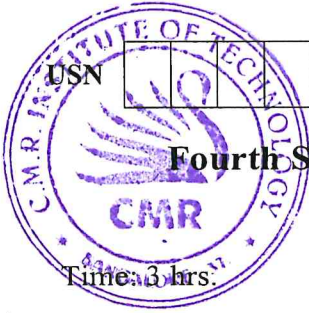


CBCS SCHEME



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18EC42

Fourth Semester B.E. Degree Examination, July/August 2022

Analog Circuits

Time: 3 hrs.

Max. Marks: 100

Note: Answer any FIVE full questions, choosing ONE full question from each module.

Module-1

- 1 a. Explain the working of voltage dividing bias circuit using BJT. (08 Marks)
- b. Design MOSFET drain to gate feedback circuit to establish $I_D = 0.5 \text{ mA}$ and $V_{DD} = 5\text{V}$. MOSFET parameters are : $V_t = 1 \text{ V}$, $K'_n(W/L) = 1 \text{ mA/V}^2$ and $\lambda = 0$. Use Standard resistor values and actual values obtained for I_D and V_D . (06 Marks)
- c. Derive an expression for voltage gain A_V of small signal CE BJT amplifier. (06 Marks)

OR

- 2 a. Explain with neat circuit diagram the MOSFET drain to gate feedback resistor biasing. (06 Marks)
- b. Design a voltage divider bias network using a supply of 24V, $\beta = 110$ and $I_{CQ} = 4 \text{ mA}$, $V_{CEQ} = 8\text{V}$. Choose $V_E = V_{CC} / 8$. (08 Marks)
- c. Explain with neat circuit diagram MOSFET circuit using fixing V_G . (06 Marks)

Module-2

- 3 a. Derive the expression for characterizing parameters of CS MOSFET amplifier without source resistor using hybrid- π equivalent circuit. (06 Marks)
- b. A phase shift oscillator is to be designed with FET having $g_m = 5000 \mu\text{s}$, $r_d = 40 \text{ k}\Omega$ while the resistance in the feedback circuit is $9.7 \text{ k}\Omega$. Select the proper value of C and R_D to have the frequency of oscillations as 5 kHz. (08 Marks)
- c. Write a note on three basic configurations of MOSFET amplifier. (06 Marks)

OR

- 4 a. State Barkhausen criteria. (04 Marks)
- b. A Quartz crystal has constants $L = 50 \text{ mH}$, $C_1 = 0.02 \text{ pF}$, $R = 500\Omega$ and $C_2 = 12 \text{ pF}$. Find the values of series and parallel resonant frequencies. Also if the external capacitance across the crystal changes from 5 pF to 6 pF, find the change in frequency of oscillations. (08 Marks)
- c. Draw and explain the frequency response characteristics of CS MOSFET amplifier. (08 Marks)

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Module-3

- 5 a. Briefly explain the four basic feedback topologies with necessary block diagram. (10 Marks)
- b. Show that the maximum efficiency of series fed, directly coupled class A power amplifier is 25%. (06 Marks)
- c. An amplifier without negative feedback has a voltage gain of 400 with a distortion of 10%. Determine the amplifier voltage gain and distortion, when a negative feedback is applied with feedback ratio of 0.01. (04 Marks)

Important Note : 1. On completing your answers, compulsorily draw diagonal cross lines on the remaining blank pages.
2. Any revealing of identification, appeal to evaluator and /or equations written eg, 42+8 = 50, will be treated as malpractice.

OR

- 6 a. With neat circuit diagram, explain the operation of a class B pushpull amplifier with relevant waveforms. Show that the maximum conversion efficiency of class B pushpull amplifier is 78.5%. (10 Marks)
- b. For a class C tuned amplifier with load resistance of $10\text{ k}\Omega$ and $V_{CC} = 30\text{V}$. Calculate
 (i) Output power if the output voltage is 30 V_{pp} .
 (ii) DC input power if current drain is 0.5 mA .
 (iii) Efficiency. (04 Marks)
- c. Derive the expression for input resistance for a voltage shunt feedback amplifier. (06 Marks)

Module-4

- 7 a. State the ideal characteristics of op-Amp. (08 Marks)
- b. For a Schmitt trigger shown in the Fig.Q7(b) calculate threshold voltage levels and hysteresis. Assume $V_{sat} = 0.9 V_c$.

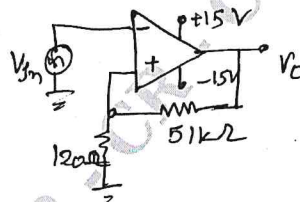


Fig. Q7(b)

- c. Draw a practical inverting amplifier and derive the expression for closed loop voltage gain, input resistance and output resistance. (08 Marks)

OR

- 8 a. Draw the circuit of 3 op-Amp instrumentation amplifier and derive expression for its output voltage. (08 Marks)
- b. Explain the working of zero crossing detector. (06 Marks)
- c. For a non-inverting amplifier, the values of R_1 and R_f are $1\text{ k}\Omega$ and $10\text{ k}\Omega$ respectively. The various op-Amp parameters are, open loop gain = 2×10^5 , Input resistance = $2\text{ M}\Omega$, Output resistance = 75Ω , Single break frequency = 5 Hz , Supply voltages = $\pm 12\text{V}$, Calculate the closed loop gain, input resistance, output resistance with feedback and bandwidth with feedback. (06 Marks)

Module-5

- 9 a. Draw and explain the working of precision full wave rectifier. (08 Marks)
- b. Design a low pass filter using op-Amp at a cutoff frequency of 1 kHz with pass gain of 2. (06 Marks)
- c. Explain the working of pulse width modulator using IC555 with waveforms. (06 Marks)

OR

- 10 a. Explain the functional block diagram of IC555. (08 Marks)
- b. Design a monostable 555 timer circuit to produce an output pulse of 10 sec wide. Draw the circuit diagram. (04 Marks)
- c. Explain with neat circuit diagram the operation of R-2R digital to analog converter. (08 Marks)

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